

Contents

chapter 1	Definition and History	1
1.1	Definition, 1	
1.2	History, 2	
chapter 2	Infrared Sources	11
2.1	Definition of Terms, 12	
2.2	Emission from Heated Bodies, 13	
2.2.1	<i>Kirchhoff's law</i> , 14	
2.2.2	<i>The Stefan-Boltzmann law</i> , 15	
2.3	Wavelength Distribution, 20	
2.3.1	<i>The Rayleigh-Jeans expression</i> , 20	
2.3.2	<i>The Planck radiation formula</i> , 24	
2.3.3	<i>The Wien displacement law</i> , 29	
2.4	The Exchange of Radiant Power between Two Bodies, 38	
2.4.1	<i>The geometrical effects</i> , 38	
2.4.2	<i>The goniometric emitting and absorbing characteristics of surfaces</i> , 42	
2.4.3	<i>Examples</i> , 48	
2.5	Time Distribution, 53	
2.5.1	<i>Coherence</i> , 54	
2.5.2	<i>Power fluctuations due to the rate at which photons are emitted by a source</i> , 57	
2.5.3	<i>Fluctuations in number of photons</i> , 59	
2.6	Line and Band Sources—Introduction, 60	
2.6.1	<i>Stationary states and line spectra</i> , 61	
2.6.2	<i>Matter waves and wave mechanics</i> , 62	
2.6.3	<i>Vibration-rotation spectra</i> , 63	

2.6.4 <i>Polyatomic molecules</i> , 66	
2.6.5 <i>Normal modes and normal coordinates</i> , 67	
2.6.6 <i>Line breadth</i> , 69	
2.7 Practical Sources, 71	
2.8 Sources Encountered outside the Laboratory, 75	
2.9 Other Sources, 78	
2.10 Useful Approximations for Engineering Calculations, 84	
chapter 3 The Theory of the Infrared Optical Characteristics of Media	87
3.1 Introduction and General Discussion, 87	
3.2 Electromagnetic Theory, 88	
3.2.1 <i>Maxwell's equations</i> , 88	
3.2.2 <i>The wave equations and optical constants</i> , 90	
3.3 Electromagnetic Power Flow, 95	
3.4 Media Discontinuities, 96	
3.4.1 <i>Boundary conditions</i> , 97	
3.4.2 <i>Refraction and Snell's law</i> , 98	
3.4.3 <i>Reflection</i> , 98	
3.5 Absorption, Dispersion and, Scattering, 101	
3.5.1 <i>Absorption and dispersion</i> , 102	
3.5.2 <i>Scattering</i> , 107	
3.6 Interference and Diffraction, 109	
3.6.1 <i>Interference</i> , 110	
3.6.2 <i>Diffraction</i> , 112	
chapter 4 Optical Properties of Media	119
4.1 Introduction, 119	
4.2 Class of Matter—Their Optical Properties, 119	
4.2.1 <i>Solids</i> , 119	
4.2.2 <i>Liquids</i> , 127	
4.2.3 <i>Gases</i> , 128	
4.3 Choice of Specific Materials, 128	
4.3.1 <i>Requirements for windows</i> , 128	
4.3.2 <i>Requirements for domes</i> , 129	
4.3.3 <i>Other optical components</i> , 131	
4.3.4 <i>Available materials</i> , 138	
chapter 5 Optical Properties of the Atmosphere	162
5.1 Introduction, 162	
5.2 Description of the Atmosphere, 163	
5.3 Molecular Absorption—Theory, 167	
5.4 Molecular Absorption—Empirical Discussion, 172	

5.5	Scattering by the Atmosphere—Theory, 181	
5.5.1	<i>Geometrical optics approach</i> , 183	
5.5.2	<i>Electromagnetic theory approach—Mie's theory</i> , 186	
5.6	Scattering by the Atmosphere—Empirical Discussion, 189	
chapter 6	The Physics of Semiconductors	194
6.1	Introduction, 194	
6.2	The Periodic Lattice, 194	
6.3	Energy Bands in a Perfect Crystal, 197	
6.4	Imperfections in the Lattice, 200	
6.5	Fermi-Dirac Statistics for an Intrinsic Semiconductor, 204	
6.6	Fermi-Dirac Statistics for an Extrinsic Semiconductor, 208	
6.7	Electrical Conductivity and the Hall Effect, 210	
6.8	Recombination and Lifetime, 219	
6.9	Motion of Carriers in the Presence of Electric and Magnetic Fields, 222	
6.10	Rectifying Junctions, 228	
chapter 7	Sources of Noise	235
7.1	Introduction, 235	
7.2	Thermal Noise—Nyquist Theorem, 236	
7.3	Noise in Electron Tubes, 241	
7.3.1	<i>Shot noise in saturated and exponential diodes</i> , 242	
7.3.2	<i>Shot noise in space charge limited diodes</i> , 246	
7.3.3	<i>Shot noise in triodes</i> , 247	
7.3.4	<i>Partition noise</i> , 249	
7.3.5	<i>Flicker noise</i> , 249	
7.3.6	<i>Microphonics</i> , 249	
7.3.7	<i>Noise resistances of selected receiving tubes</i> , 251	
7.4	Noise in Semiconductors, 251	
7.4.1	<i>Current noise</i> , 253	
7.4.2	<i>Generation-recombination noise</i> , 255	
7.5	Noise in Transistors and Diodes, 258	
7.6	Noise in Transformers, 260	
7.7	Noise in Galvanometers, 261	
chapter 8	Phenomenological Description of Infrared Detection Mechanisms	265
8.1	The Infrared Detector, 265	
8.2	Figures of Merit, 268	
8.3	Photon Effects, 277	
8.3.1	<i>Photoemissive effect</i> , 277	
8.3.2	<i>Photoconductivity</i> , 288	
8.3.3	<i>Photovoltaic effect</i> , 296	
8.3.4	<i>Photoelectromagnetic effect</i> , 299	

8.3.5	<i>Dember effect</i> , 300	
8.3.6	<i>Filterscan tube</i> , 301	
8.3.7	<i>Phosphors</i> , 302	
8.3.8	<i>Microwave effects</i> , 305	
8.3.9	<i>Narrow band quantum counters</i> , 306	
8.3.10	<i>Photographic film</i> , 308	
8.4	Thermal Effects, 308	
8.4.1	<i>Metal and thermistor bolometers</i> , 309	
8.4.2	<i>Superconducting bolometer</i> , 312	
8.4.3	<i>Thermocouple and thermopile</i> , 313	
8.4.4	<i>Golay cell</i> , 314	
8.4.5	<i>Evaporograph</i> , 315	
8.4.6	<i>Absorption edge image converter</i> , 316	
chapter 9	Mathematical Analyses of Selected Detection Mechanisms and of the Photon Noise Limit	321
9.1	Introduction, 321	
9.2	Noise in Detectors, 322	
9.3	Mathematical Theory of Selected Detection Mechanisms, 324	
9.3.1	<i>Photoconductivity</i> , 327	
9.3.2	<i>Photoelectromagnetic effect</i> , 333	
9.3.3	<i>Photovoltaic effect</i> , 337	
9.3.4	<i>Bolometer</i> , 345	
9.4	Theoretical Performance of Photon Noise Limited Detectors, 349	
9.4.1	<i>Photon noise limitations of thermal detectors</i> , 351	
9.4.2	<i>Temperature noise in thermal detectors</i> , 354	
9.4.3	<i>Photon noise limitations of photon detectors</i> , 356	
9.4.4	<i>Photon noise limit of a narrow band quantum counter</i> , 371	
9.4.5	<i>Signal fluctuation limit</i> , 376	
9.5	Means of Achieving Photon Noise Limited Performance, 377	
	Appendix I. Determination of $D_{\lambda}^*(\lambda, f, \Delta f)$ from $D^*(T, f, \Delta f)$	
	384	
	Appendix II. Havens' Limit, 385	
chapter 10	Comparative Performance of Elemental Detectors	386
10.1	Introduction, 386	
10.2	Some General Remarks Concerning Elemental Photon Detectors, 389	
10.2.1	<i>Comparison of thin film and single crystal detectors</i> , 389	
10.2.2	<i>Comparison of extrinsic and intrinsic materials</i> , 390	
10.2.3	<i>Detector impedance</i> , 391	
10.2.4	<i>Size and shape of sensitive area</i> , 392	

10.2.5	<i>Temperature of operation</i> , 393
10.2.6	<i>Photocell housings</i> , 393
10.2.7	<i>Infrared transmitting windows and immersion optics</i> , 398
10.3	The Lead Salt Photoconductors, 399
10.3.1	<i>Lead sulfide</i> (PbS), 399
10.3.2	<i>Lead selenide</i> (PbSe), 402
10.3.3	<i>Lead telluride</i> (PbTe), 403
10.4	Germanium, 404
10.4.1	<i>Gold-doped germanium</i> (Ge:Au), <i>p-type</i> , 404
10.4.2	<i>Gold, antimony-doped</i> (Ge:Au,Sb), <i>n-type</i> , 405
10.4.3	<i>Zinc-doped germanium</i> (Ge:Zn), “Zip”, 406
10.4.4	<i>Zinc, antimony-doped</i> (Ge:Zn,Sb), 407
10.4.5	<i>Copper-doped germanium</i> (Ge:Cu), 407
10.4.6	<i>Cadmium-doped germanium</i> (Ce:Cd), 407
10.4.7	<i>Germanium-silicon alloys</i> (Ge-Si:Au;Ge-Si:Zn,Sb), 408
10.5	Indium Antimonide (InSb), 409
10.5.1	<i>Photoconductive mode</i> , 409
10.5.2	<i>Photovoltaic mode</i> , 410
10.5.3	<i>Photoelectromagnetic mode</i> , 411
10.6	Indium Arsenide (InAs), 411
10.7	Tellurium (Te), 412
10.8	Thallous Sulfide (Tl ₂ S), 412
10.9	Mercury Telluride-Cadmium Telluride (HgTe-CdTe), 413
10.10	Thermistor Bolometer, 414
10.11	Superconducting Bolometer, 414
10.12	Carbon Bolometer, 415
10.13	Radiation Thermocouple, 416
10.14	Golay Cell, 416
10.15	Detectors for the Visible Spectrum, 417
10.15.1	<i>Cadmium sulfide</i> (CdS), 417
10.15.2	<i>Cadmium selenide</i> (CdSe), 418
10.15.3	<i>Selenium-selenium oxide</i> (Se-SeO), 418
10.15.4	<i>Gallium arsenide</i> (GaAs), 418
10.15.5	<i>1N2175 silicon photo-duo-diode</i> , 418
10.15.6	<i>1P21 photomultiplier</i> , 419

Some Useful Engineering Approximations	436
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Appendix I.	Ratio of $D_{\lambda_P}^*(\lambda_P, f, \Delta f)$ to $D^*(500^\circ \text{ K}, f, \Delta f)$ for Selected Detectors
Appendix II.	Approximate Method for Converting the Value of $D^*(T_1, f, \Delta f)$ to $D^*(T_2, f, \Delta f)$
Appendix III.	Useful Frequency Range of a Detector

Index	439
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